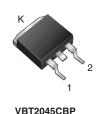


Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.33 \text{ V}$ at $I_F = 5.0 \text{ A}$

TMBS® TO-263AB



PIN 1 O	K
-	— 0
PIN 2 O	HEATSINK

PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V_{RRM}	45 V			
I _{FSM}	160 A			
V _F at I _F = 10 A	0.41 V			
T _{OP} max. (AC mode)	150 °C			
T _J max. (DC forward current)	200 °C			
Package	TO-263AB			
Diode variations	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



- T_J 200 °C max. in solar bypass mode application
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VBT2045CBP	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)} ⁽¹⁾	20	А
	per diode		10	
Peak forward surge current 8.3 ms single half sine-w superimposed on rated load per diode	I _{FSM}	160	А	
Operating junction and storage temperature range (AC mode)		T _{OP} , T _{STG}	-40 to +150	°C
Junction temperature in DC forward current without reverse bias, $t \le 1 \text{ h}$		T _J ⁽²⁾	≤ 200	°C

Notes

- (1) With heatsink
- (2) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V
	I _F = 10 A			0.49	0.58	
	I _F = 5 A	T _A = 125 °C		0.33	-	
	I _F = 10 A			0.41	0.52	
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	2000	μΑ
	v _R = 45 v	T _A = 125 °C		10	30	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL VBT2045CBP		UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	3.0	°C/W	
	per device		2.0]	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT2045CBP-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VBT2045CBP-E3/8W	1.38	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

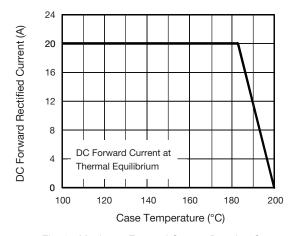


Fig. 1 - Maximum Forward Current Derating Curve

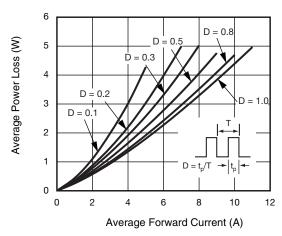


Fig. 2 - Forward Power Loss Characteristics Per Diode



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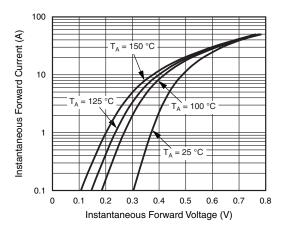


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

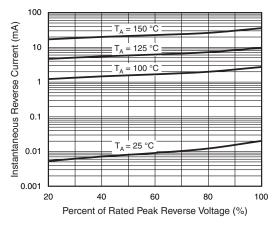


Fig. 4 - Typical Reverse Characteristics Per Diode

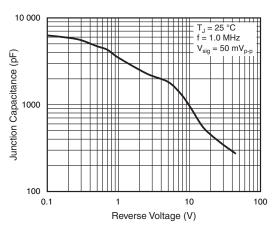


Fig. 5 - Typical Junction Capacitance Per Diode

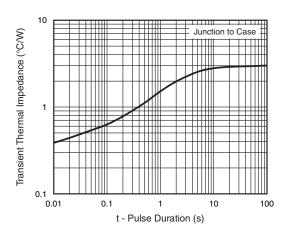


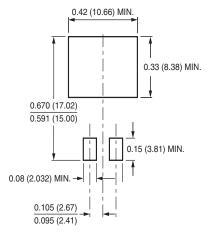
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.055 (1.40) 0.160 (4.06) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) Κ -0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.110 (2..., 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

TO-263AB

Mounting Pad Layout





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Vishay

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